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## Piezoelectric characteristics of CMOS compatible AlN SAW resonators

(Conference Paper)

Ralib, A.A.M.<sup>a</sup>, Pandian, M.S.<sup>b</sup>, Ferrer, E.M.<sup>b</sup>, Song, C.T.<sup>b</sup>, Shunmugam, M.<sup>b</sup>, Zainuddin, A.A.B.<sup>b</sup>, Nordin, A.N.<sup>a</sup>

<sup>a</sup>Electrical and Computer Engineering Department, Kulliyah of Engineering, International Islamic University Malaysia, Malaysia

<sup>b</sup>Silterra Malaysia, Lot 8, Phase II, Kulim Hi-Tech Park, Kedah, Malaysia

### Abstract

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In this work, we predict the surface acoustic wave characteristics by 2D COMSOL finite element modeling. The dispersion of simulated acoustic mode shapes, acoustic phase velocity and coupling coefficient were performed on a CMOS-compatible 1.4 GHz SAW resonator. C-axis oriented Aluminium Nitride (AlN) was chosen as the piezoelectric material due to its compatibility with CMOS technology and higher phase velocity. The influences of AlN thickness on electromechanical coupling coefficient and phase velocity are discussed. High acoustic velocities ( $v \sim 5220$  m/s) and coupling factors ( $k^2 \sim 0.19\%$ ) can be observed for SAW resonator with  $kh_{AlN} \sim 3.9$ . The measurement results are found to be consistent with FEM results with deviation less than 6% for resonance frequency and phase velocity. Copyright 2014 IEICE.

### Author keywords

Aluminium nitride CMOS Coupling coefficient Piezoelectric Surface acoustic wave

### Indexed keywords

Engineering controlled terms:	Acoustic surface wave devices	Acoustic wave velocity measurement	Acoustic waves	Acoustics
	Aluminum	Aluminum nitride	C (programming language)	CMOS integrated circuits
	Couplings	Electromechanical coupling	Finite element method	Nitrides
	Piezoelectricity	Resonators		Phase velocity

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## References (10)

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- 1 Du, X.  
(2012) *Design and Fabrication of a Prototype Aluminum Nitride-Based Pressure Sensor with Finite Element Analysis and Validation*. Cited 2 times.  
Proquest, UMI Dissertation Publishing
- 2 Ramli, N.A., Nordin, A.N.  
Design and modeling of MEMS SAW resonator on Lithium Niobate  
  
(2011) *2011 4th International Conference on Mechatronics: Integrated Engineering for Industrial and Societal Development, ICOM'11 - Conference Proceedings*, art. no. 5937127. Cited 2 times.  
doi: 10.1109/ICOM.2011.5937127  
  
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- 3 Kar, J.P., Bose, G.  
*Aluminum Nitride (AlN) Film Based Acoustic Devices: Material Synthesis and Device Fabrication*
- 4 Nordin, A.N., Zaghloul, M.E.  
Modeling and fabrication of CMOS surface acoustic wave resonators  
  
(2007) *IEEE Transactions on Microwave Theory and Techniques*, 55 (5), pp. 992-1001. Cited 26 times.  
doi: 10.1109/TMTT.2007.895408  
  
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- 5 Kar, J.P., Bose, G.  
*Aluminum Nitride (AlN) Film Based Acoustic Devices: Material Synthesis and Device Fabrication*

- 
- 6 Neculoiu, D., Müller, A., Deligeorgis, G., Dinescu, A., Stavrinidis, A., Vasilache, D., Cismaru, A.M., (...), Konstantinidis, G.

AlN on silicon based surface acoustic wave resonators operating at 5GHz

(2009) *Electronics Letters*, 45 (23), pp. 1196-1197. Cited 30 times.  
doi: 10.1049/el.2009.2520

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- 
- 7 Kannan, T.  
(2006) *Finite Element Analysis of Surface Acoustic Wave Resonators*. Cited 19 times.

- 
- 8 Tigli, O., Zaghloul, M.E.

Finite element modeling and analysis of surface acoustic wave devices in CMOS technology

(2012) *IEEE Transactions on Components, Packaging and Manufacturing Technology*, 2 (6), art. no. 6092471, pp. 1021-1029. Cited 7 times.  
doi: 10.1109/TCPMT.2011.2170572

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- 
- 9 Kaletta, U.C., Wenger, C.  
FEM simulation of rayleigh waves for CMOS compatible SAW devices based on AlN/SiO<sub>2</sub>/Si(100)  
(2013) *Ultrasonics*, pp. 1-5.  
May

- 
- 10 Visser, J.H., Vellekoop, M.J., Venema, A., van der Drift, E., Rek, P.J.M., Nederlof, A.J., Nieuwenhuizen, M.S.  
Surface acoustic wave filters in ZnO-SiO<sub>2</sub>-Si layered structures

(1989) *Ultrasonics Symposium Proceedings*, 1, pp. 195-200. Cited 13 times.

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